

SNx5LBC182 Differential Bus Transceiver

1 Features

- One-fourth unit load allows up to 128 devices on a bus
- Meets or exceeds the requirements of ANSI standard TIA/EIA-485-A and ISO 8482: 1987(E)
- Controlled driver output-voltage slew rates allow longer cable stub lengths
- Designed for signaling rates.
 - The signaling rate of a line, is the number of voltage transitions that are made per second expressed in the units bps (bits per second) up to 250 kbps
- Low disabled supply current: 250- μ A maximum
- Thermal shutdown protection
- Open-circuit fail-safe receiver design
- Receiver input hysteresis: 70-mV typical
- Glitch-free power-up and power-down protection

2 Applications

- Utility meters
- [Industrial process control](#)
- [Building automation](#)

3 Description

The SN65LBC182 and SN75LBC182 are differential data line transceivers with a high level of ESD protection in the trade-standard footprint of the SN75176. They are designed for balanced transmission lines and meet ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC182 and SN75LBC182 combine a 3-state, differential line driver and differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected together to function as a direction control.

The driver outputs and the receiver inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus. This port operates over a wide range of common-mode voltage, making the device suitable for party-line applications. The device also includes additional features for party-line data buses in electrically noisy environment applications such as industrial process control or power inverters.

The SN75LBC182 and SN65LBC182 bus pins also exhibit a high input resistance equivalent to one-fourth unit load allowing connection of up to 128 similar devices on the bus. The high ESD tolerance protects the device for cabled connections. (For an even higher level of protection, see the SN65/75LBC184, literature number SLLS236.)

The differential driver design incorporates slew-rate-controlled outputs sufficient to transmit data up to 250 kbps. Slew-rate control allows longer unterminated cable runs and longer stub lengths from the main backbone than possible with uncontrolled voltage transitions. The receiver design provides a fail-safe output of a high level when the inputs are left floating (open circuit). Very low device supply current can be achieved by disabling the driver and the receiver.

The SN65LBC182 is characterized for operation from -40°C to 85°C , and the SN75LBC182 is characterized for operation from 0°C to 70°C .

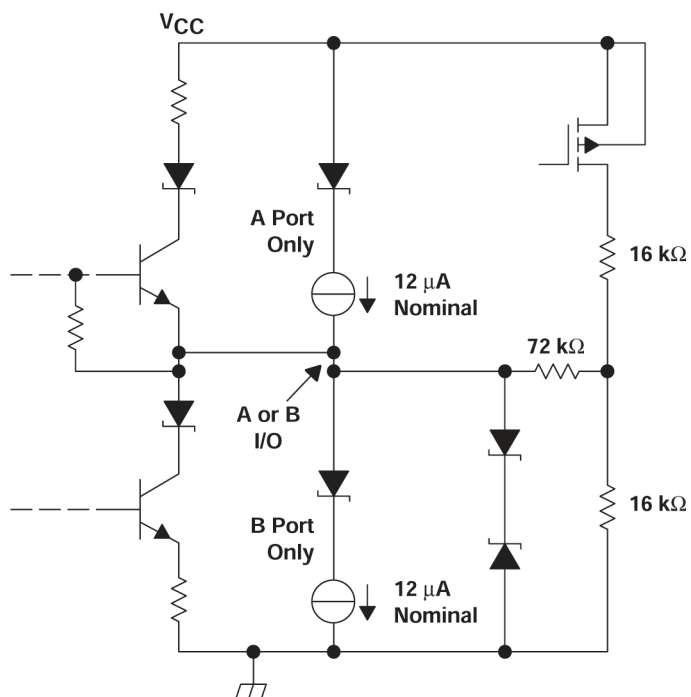
Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
SN65LBC182, SN75LBC182	P (PDIP, 8)	9.81 mm $\times$ 9.43 mm
	D (SOIC, 8)	4.9 mm $\times$ 6 mm

(1) For more information, see [Section 11](#).

(2) The package size (length $\times$ width) is a nominal value and includes pins, where applicable.





Schematic of Inputs and Outputs

Table of Contents

1 Features	1	6 Parameter Measurement Information	9
2 Applications	1	7 Detailed Description	12
3 Description	1	7.1 Functional Block Diagram.....	12
4 Pin Configuration and Functions	4	7.2 Device Functional Modes.....	12
5 Specifications	5	8 Application and Implementation	13
5.1 Absolute Maximum Ratings	5	8.1 Application Information.....	13
5.2 ESD Ratings.....	5	9 Device and Documentation Support	14
5.3 Dissipation Rating.....	5	9.1 Receiving Notification of Documentation Updates....	14
5.4 Recommended Operating Conditions.....	5	9.2 Support Resources.....	14
5.5 Thermal Information.....	6	9.3 Trademarks.....	14
5.6 Driver Electrical Characteristics.....	6	9.4 Electrostatic Discharge Caution.....	14
5.7 Receiver Electrical Characteristics.....	6	9.5 Glossary.....	14
5.8 Driver Switching Characteristics.....	7	10 Revision History	14
5.9 Receiver Switching Characteristics.....	7	11 Mechanical, Packaging, and Orderable	
5.10 Typical Characteristics.....	8	Information	14

4 Pin Configuration and Functions

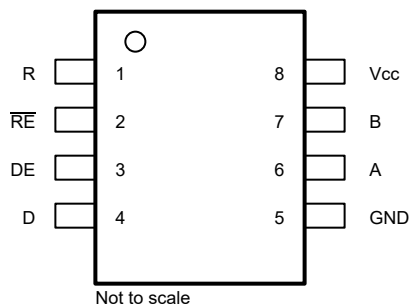


**Figure 4-1. P (PDIP) or D (SOIC) Package
(Top View)**

Table 4-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
R	1	O	Receiver Output
$\overline{RE}$	2	I	Active Low Receiver Enable Input
DE	3	I	Active High Driver Enable Input
D	4	I	Driver Input
GND	5	GND	Device GND
A	6	I/O	Non-Inverting Differential Bus I/O
B	7	I/O	Inverting Differential Bus I/O
V _{CC}	8	PWR	Device VCC (4.75V to 5.25V)

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range unless otherwise noted⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage range, (see ⁽²⁾)	-0.5	7	V
(A or B)	Voltage range at any bus terminal	-15	15	V
V _I (D, DE, R or RE)	Input voltage	-0.3	7	V
I _O	Receiver output current		±20	mA
	Continuous total power dissipation	See <i>Dissipation Rating</i> table		

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	A, B, GND	±15
			All pins	±3
		IEC 61000-4-2 contact discharge	A, B, GND	±8
		IEC 61000-4-2 Air-gap discharge	A, B, GND	±15

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Dissipation Rating

PACKAGE ⁽²⁾	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW
P	1150 mW	9.2 mW/°C	736 mW	598 mW

- (1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.
- (2) The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature

5.4 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus I/O terminal (separately or common mode) V _I or V _{IC}		−7		12	V
High-level input voltage, V _{IH}	D, DE, RE	2		0.8	V
Low-level input voltage, V _{IL}					
Differential input voltage, V _{ID} (see ⁽¹⁾)		−12		12	V
Output current, I _O	Driver	−60		60	mA
	Receiver	−8		4	
Operating free-air temperature, T _A	SN65LBC182	−40		85	°C
	SN75LBC182	0		70	

- (1) Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

5.5 Thermal Information

THERMAL METRIC ⁽¹⁾		D (SOIC)	P (PDIP)	UNIT
		8-PINS		
R _{θJA}	Junction-to-ambient thermal resistance	116.7	84.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	56.3	65.4	°C/W
R _{θJB}	Junction-to-board thermal resistance	63.4	62.1	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	8.8	31.3	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	62.6	60.4	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.6 Driver Electrical Characteristics

over recommended operating conditions

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK}	Input clamp voltage	$I_I = -18$ mA		-1.5			V
V_O	Output voltage	$I_O = 0$		0		V_{CC}	V
$ V_{OD} $	Differential output voltage	$R_L = 54 \Omega$,	See Figure 6-1	1.5	2.2	V_{CC}	V
		$V_{test} = -7$ V to 12 V,	See Figure 6-2	1.5	2.2	V_{CC}	V
ΔV_{OD}	Change in magnitude of differential output voltage	See Figure 6-1		-0.2		0.2	V
$V_{OC(SS)}$	Steady-state common-mode output voltage			1		3	
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage	See Figure 6-1 and Figure 6-4		-0.2		0.2	
$V_{OC(PP)}$	Peak-to-peak change in common-mode output voltage during state transitions				0.8		V
I_{OZ}	High-impedance output current	See receiver input currents					
I_{IH}	High-level input current (D, DE)	$V_I = 2.4$ V				50	μA
I_{IL}	Low-level input current (D, DE)	$V_I = 0.4$ V		-50			μA
I_{OS}	Short-circuit output current	$V_O = -7$ V to 12 V		-250		250	mA
I_{CC}	Supply current	SN75LBC182	No load, DE at V_{CC} , $\overline{RE}$ at V CC		12	25	mA
		SN65LBC182			12	30	

(1) All typical values are at $V_{CC} = 5$ V and $T_A = 25^\circ\text{C}$.

5.7 Receiver Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage					0.2	V
V_{IT-}	Negative-going input threshold voltage			-0.2			
V_{hys}	Hysteresis voltage ($V_{IT+} - V_{IT-}$)				70		mV
V_{IK}	Enable-input clamp voltage	$I_I = -18$ mA		-1.5			V
V_{OH}	High-level output voltage	$V_{ID} = 200$ mV, $I_O = -8$ mA,	See Figure 6-7		2.8		V
V_{OL}	Low-level output voltage	$V_{ID} = 200$ mV, $I_O = 4$ mA,	See Figure 6-7			0.4	V

5.7 Receiver Electrical Characteristics (continued)

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
I_{OZ} High-impedance-state output current	$V_O = 0.4$ to 2.4 V			± 1	μA
I_I Bus input current	$V_{IH} = 12$ V, $V_{CC} = 5$ V			250	μA
	$V_{IH} = 12$ V, $V_{CC} = 0$ V			250	
	$V_{IH} = -7$ V, $V_{CC} = 5$ V			-200	
	$V_{IH} = -7$ V, $V_{CC} = 0$ V			-200	
I_{IH} High-level input current ($\overline{RE}$)	$V_{IH} = 2$ V			50	μA
I_{IL} Low-level input current ($\overline{RE}$)	$V_{IL} = 0.8$ V			-50	μA
I_{CC} Supply current	No load	DE at 0 V, $\overline{RE}$ at 0 V		3.5	mA
		DE at 0 V, $\overline{RE}$ at V_{CC}		175 250	μA

(1) All typical values are at $V_{CC} = 5$ V and $T_A = 25^\circ C$.

5.8 Driver Switching Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_r Differential output signal rise time	$R_L = 54 \Omega$, See Figure 6-3 $C_L = 50$ pF,	0.25	0.72	1.2	μs
t_f Differential output signal fall time		0.25	0.73	1.2	
t_{PLH} Propagation delay time, low-to-high-level output				1.3	
t_{PHL} Propagation delay time, high-to-low-level output				1.3	
$t_{sk(p)}$ Pulse skew ($t_{PHL} - t_{PLH}$)			0.075	0.15	
t_{PZH} Output enable time to high level	$R_L = 110 \Omega$, See Figure 6-5			3.5	μs
t_{PHZ} Output disable time from high level				3.5	
t_{PZL} Output enable time to low level	$R_L = 110 \Omega$, See Figure 6-6			3.5	μs
t_{PLZ} Output disable time from low level				3.5	

5.9 Receiver Switching Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_r Differential output signal rise time	$C_L = 50$ pF, See Figure 6-7		20		ns
t_f Differential output signal fall time			20		
t_{PLH} Propagation delay time, low-to-high-level output				150	
t_{PHL} Propagation delay time, high-to-low-level output				150	
t_{PZH} Output enable time to high level	See Figure 6-8			100	ns
t_{PZL} Output enable time to low level				100	
t_{PHZ} Output disable time from high level				100	ns
t_{PLZ} Output disable time from low level				100	
$t_{sk(p)}$ Pulse skew $ t_{PHL} - t_{PLH} $				50	ns

5.10 Typical Characteristics

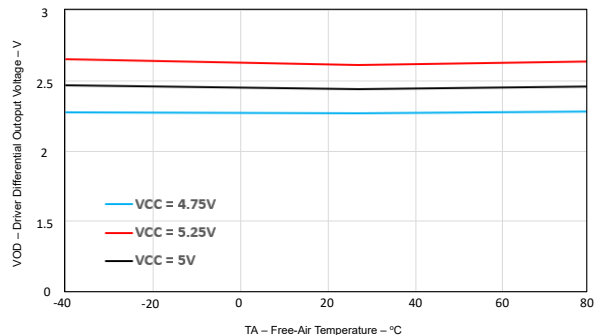


Figure 5-1. Driver Differential Output Voltage vs Temperature

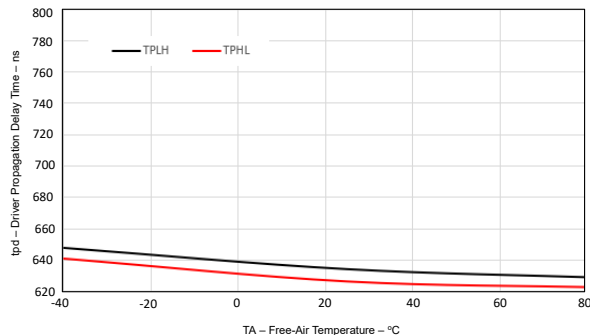


Figure 5-2. Driver Propagation Delay Time vs Temperature

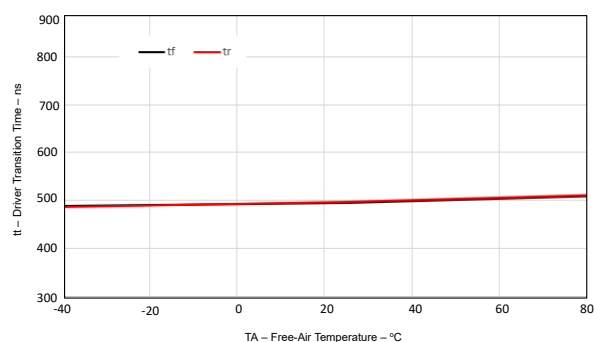


Figure 5-3. Driver Transition Time vs Temperature

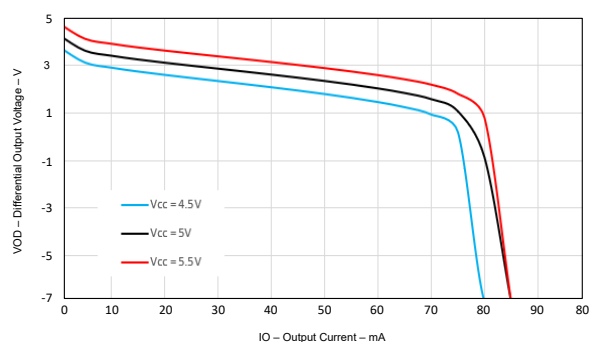


Figure 5-4. Differential Output Voltage vs Output Current

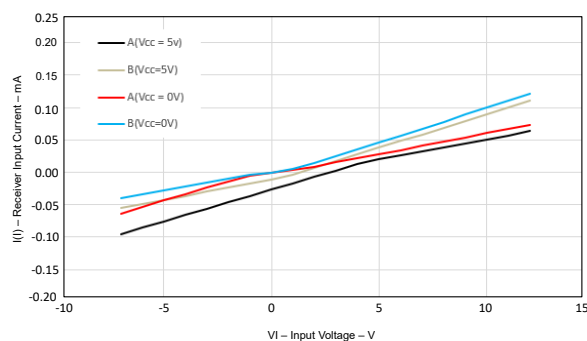
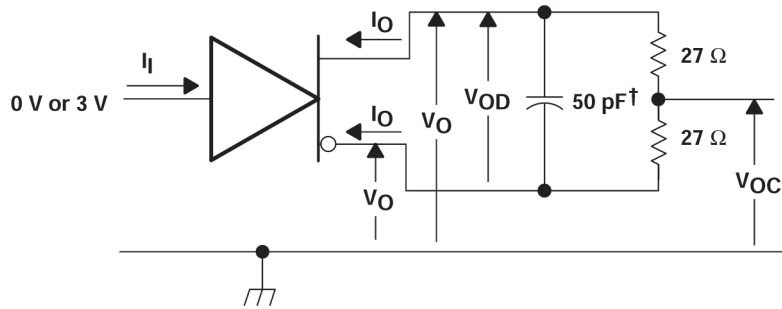


Figure 5-5. Receiver Input Current vs Input Voltage

6 Parameter Measurement Information



A. Includes probe and jig capacitance

Figure 6-1. Driver Test Circuit, v_{OD} And v_{OC} Without Common-Mode Loading

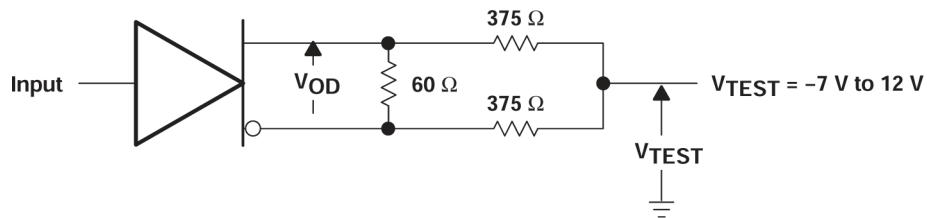
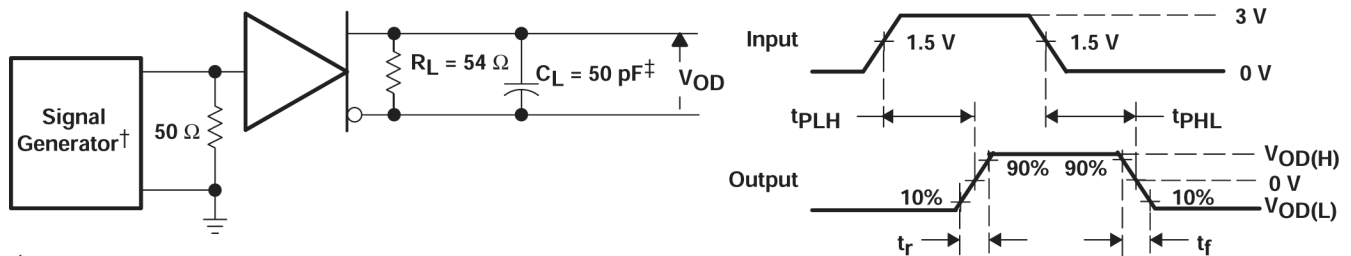


Figure 6-2. Driver Test Circuit, v_{OD} With Common-Mode Loading



- A. PRR = 1 MHz, 50% duty cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_o = 50 \Omega$
B. Includes probe and jig capacitance

Figure 6-3. Driver Switching Test Circuit and Waveforms

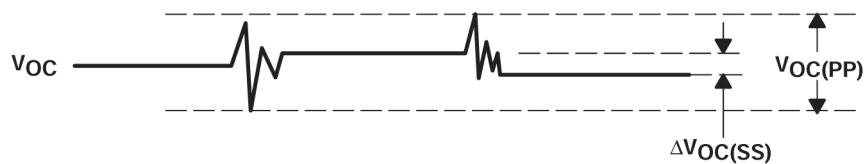
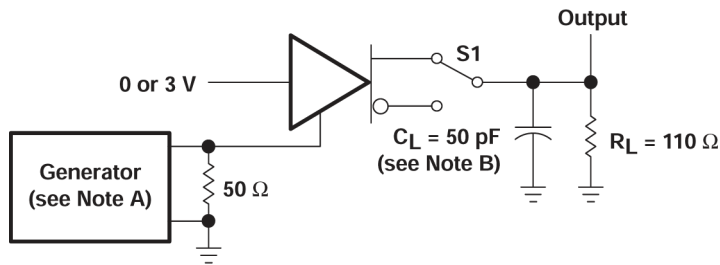
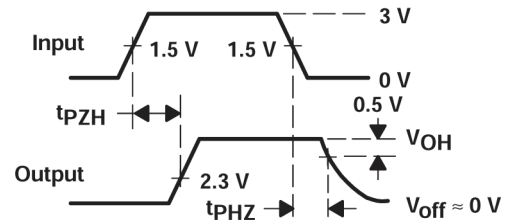


Figure 6-4. V_{OC} Definitions



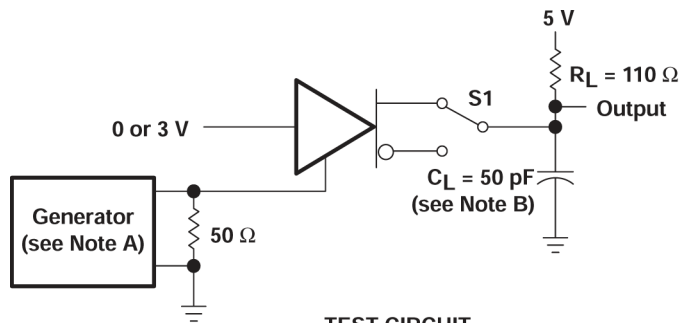
TEST CIRCUIT



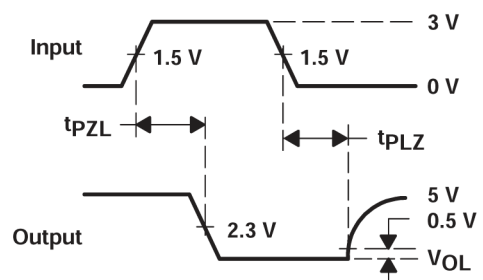
VOLTAGE WAVEFORMS

- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.

Figure 6-5. Driver T_{PZH} And T_{PHZ} Test Circuit and Voltage Waveforms



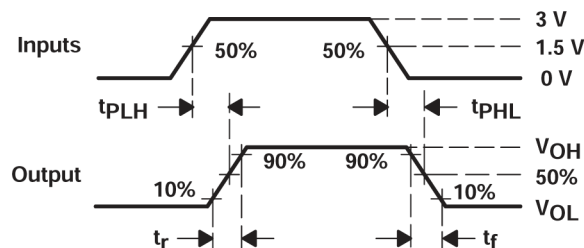
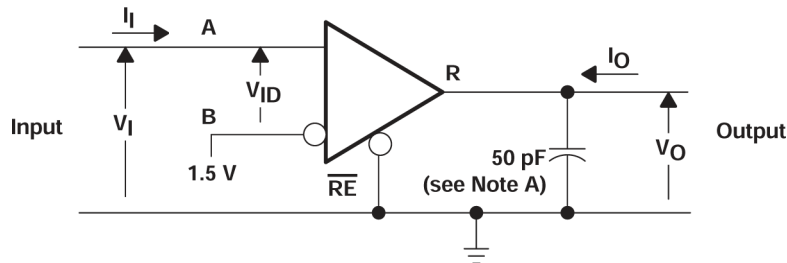
TEST CIRCUIT



VOLTAGE WAVEFORMS

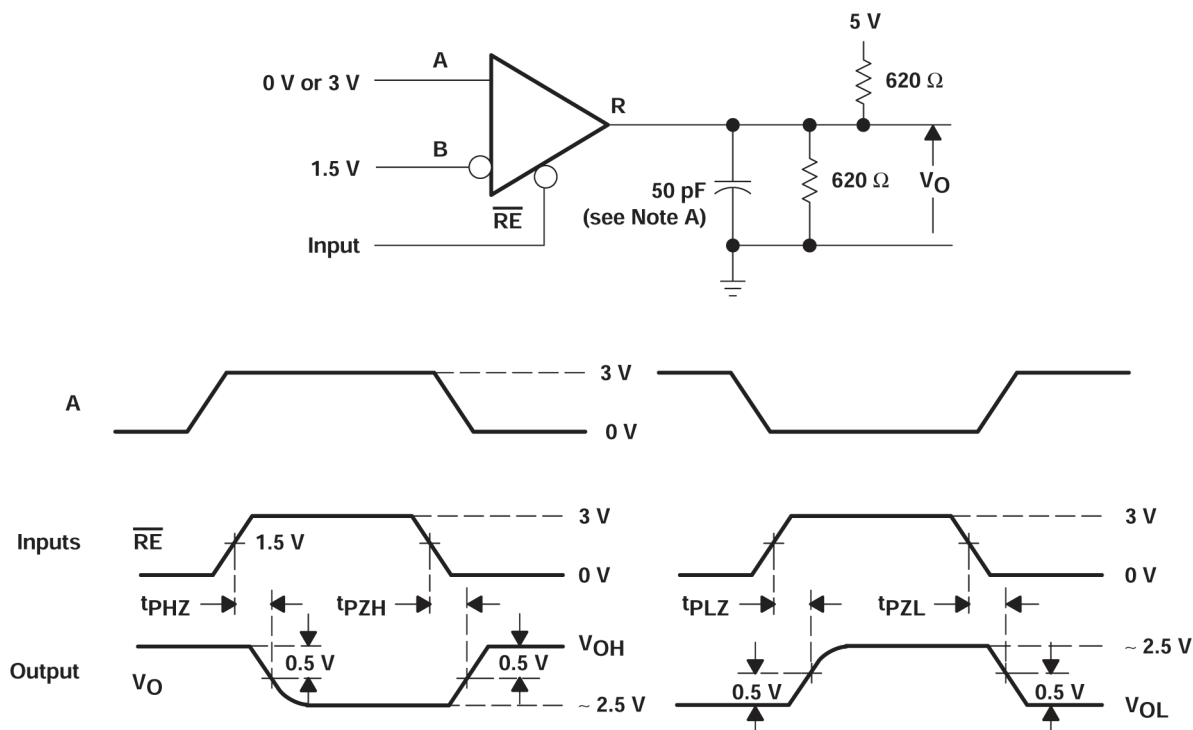
- A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns, $Z_O = 50 \Omega$.
- B. C_L includes probe and jig capacitance.

Figure 6-6. Driver T_{PZL} And T_{PLZ} Test Circuit and Voltage Waveforms



- A. This value includes probe and jig capacitance ($\pm 10\%$).

Figure 6-7. Receiver T_{PLH} And T_{PHL} Test Circuit and Voltage Waveforms

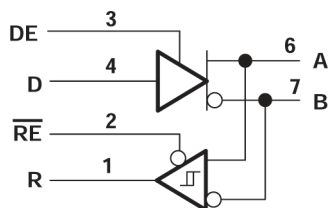


A. This value includes probe and jig capacitance ($\pm 10\%$).

Figure 6-8. Receiver T_{PZL}, T_{PLZ}, T_{PZH}, And T_{PHZ} Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Functional Block Diagram



7.2 Device Functional Modes

Table 7-1. Function Tables Driver

INPUT D	ENABLE DE	OUTPUTS	
		A	B
H	H	H	L
L	H	L	H
X	L	Z	Z
Open	H	H	L

Table 7-2. Function Tables Receiver

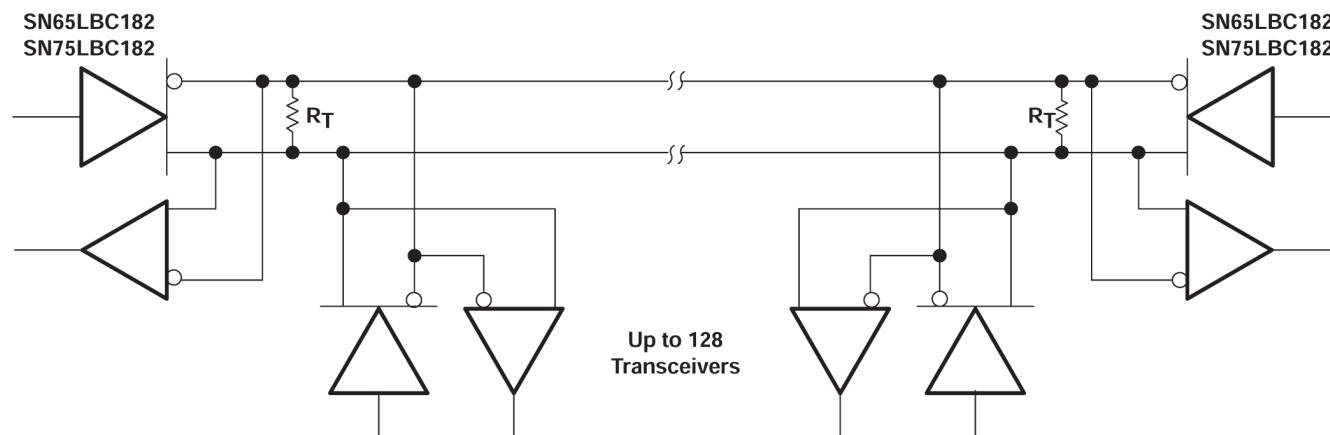
DIFFERENTIAL INPUTS	ENABLE RE	OUTPUT R
$V_{ID} \geq 0.2 \text{ V}$	L	H
$-0.2 \text{ V} < V_{ID} < 0.2 \text{ V}$	L	?
$V_{ID} \leq -0.2 \text{ V}$	L	L
X	H	Z
Open	L	H

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information



- A. The line should be terminated at both ends in its characteristic impedance ($R_T = Z_0$). Stub lengths off the main line should be kept as short as possible.

Figure 8-1. Typical Application Circuit

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (March 2005) to Revision B (October 2023)	Page
• Changed the numbering format for tables, figures, and cross-references throughout the document.....	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65LBC182D	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	6LB182
SN65LBC182DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6LB182
SN65LBC182DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6LB182
SN65LBC182DRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6LB182
SN65LBC182P	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	65LBC182
SN65LBC182P.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	65LBC182
SN75LBC182D	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	7LB182
SN75LBC182DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7LB182
SN75LBC182DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	7LB182
SN75LBC182P	Obsolete	Production	PDIP (P) 8	-	-	Call TI	Call TI	0 to 70	75LBC182

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

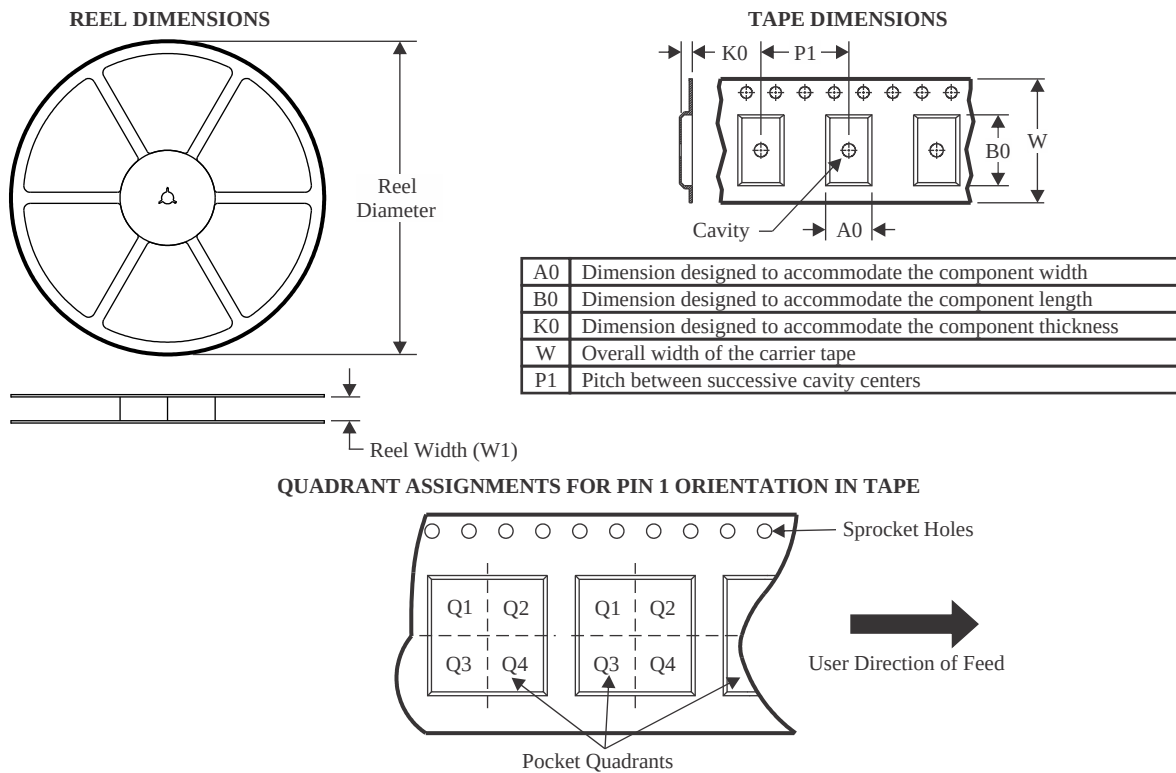
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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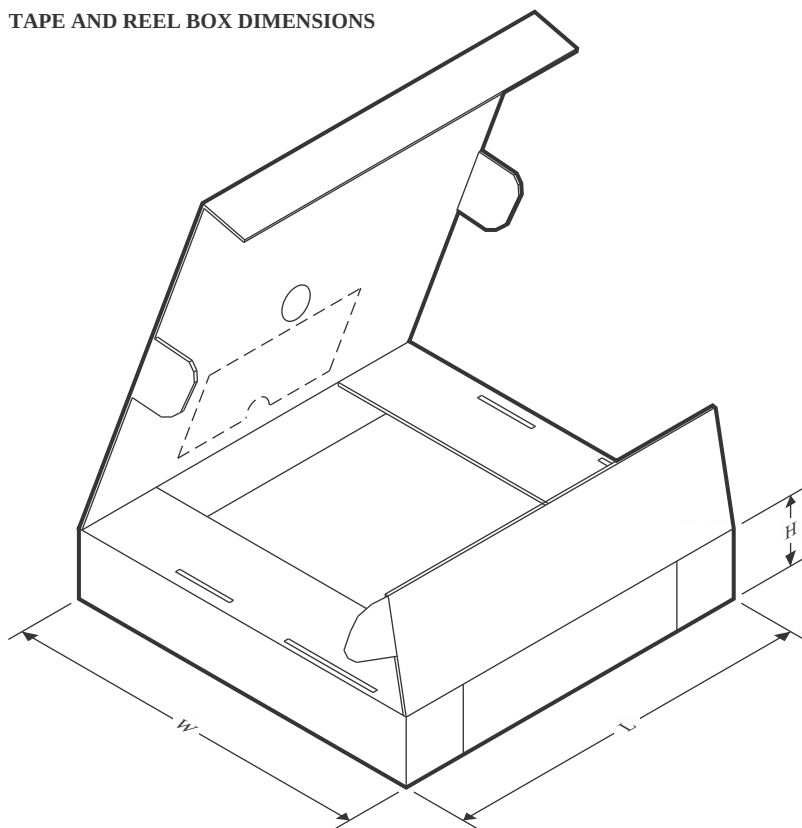
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

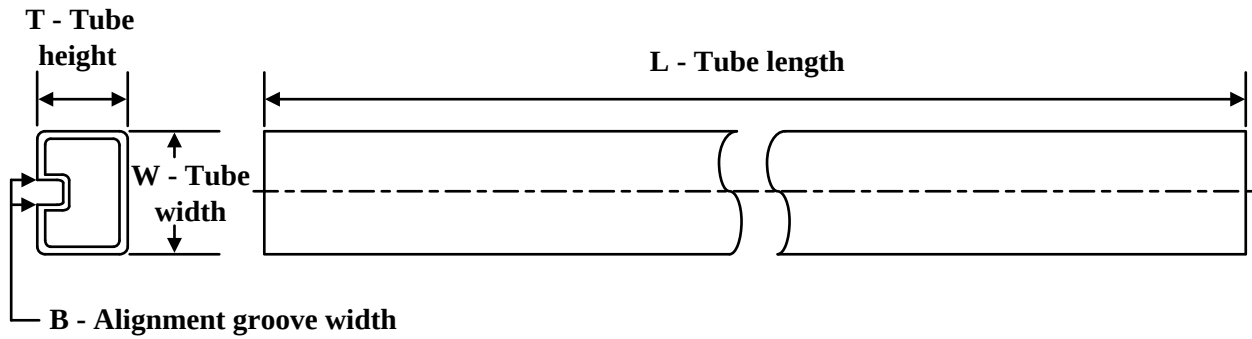
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

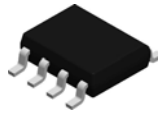
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC182DR	SOIC	D	8	2500	340.5	336.1	25.0
SN65LBC182DR	SOIC	D	8	2500	353.0	353.0	32.0
SN75LBC182DR	SOIC	D	8	2500	340.5	336.1	25.0
SN75LBC182DR	SOIC	D	8	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN65LBC182P	P	PDIP	8	50	506	13.97	11230	4.32
SN65LBC182P.A	P	PDIP	8	50	506	13.97	11230	4.32

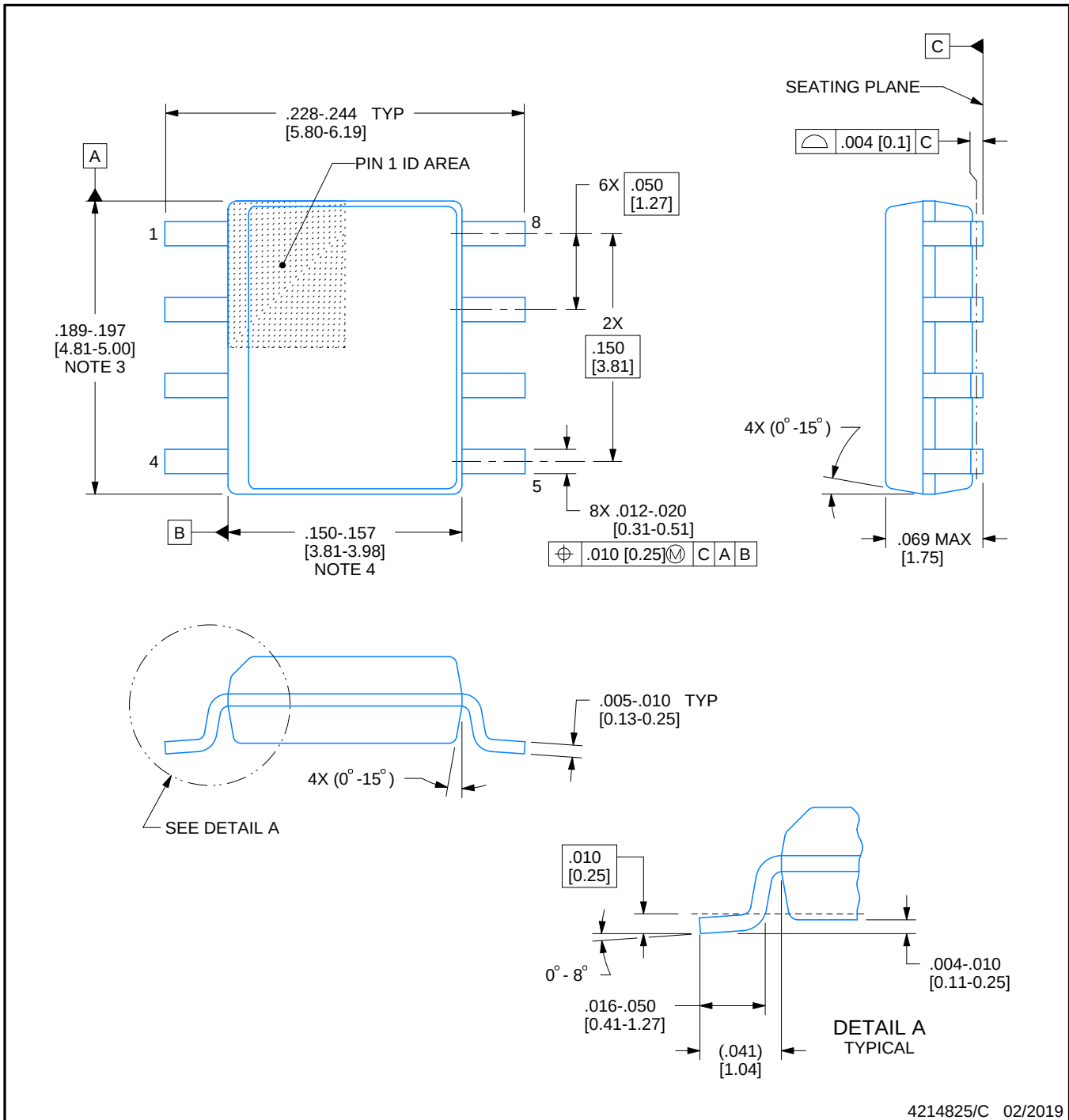


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

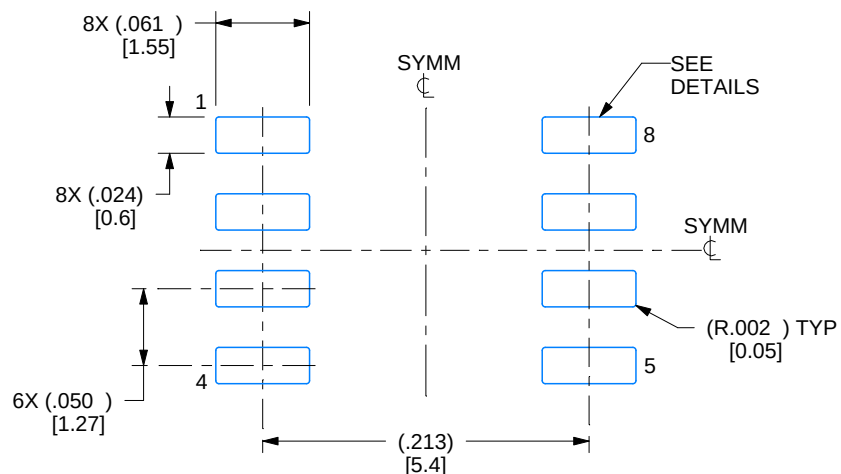
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

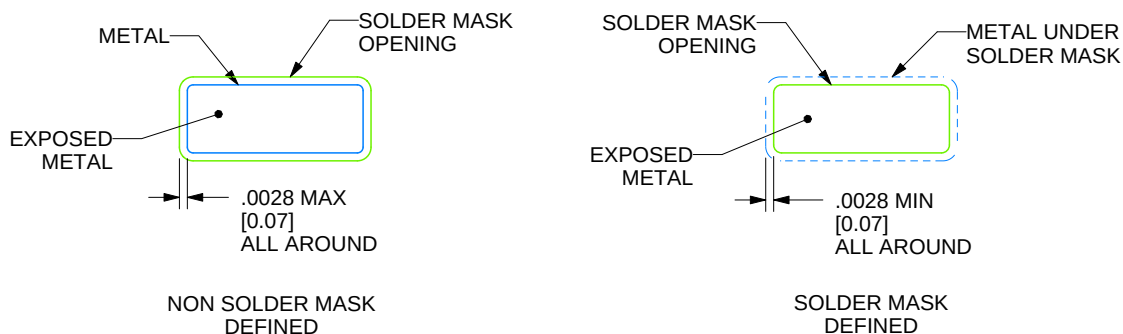
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

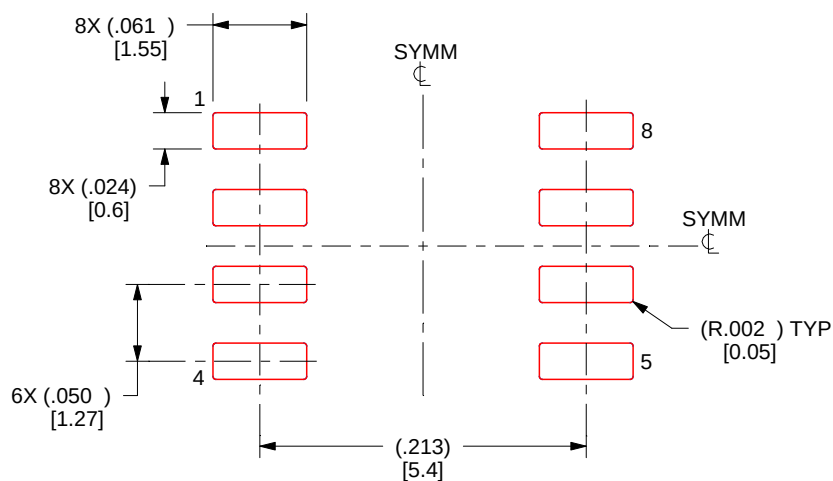
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

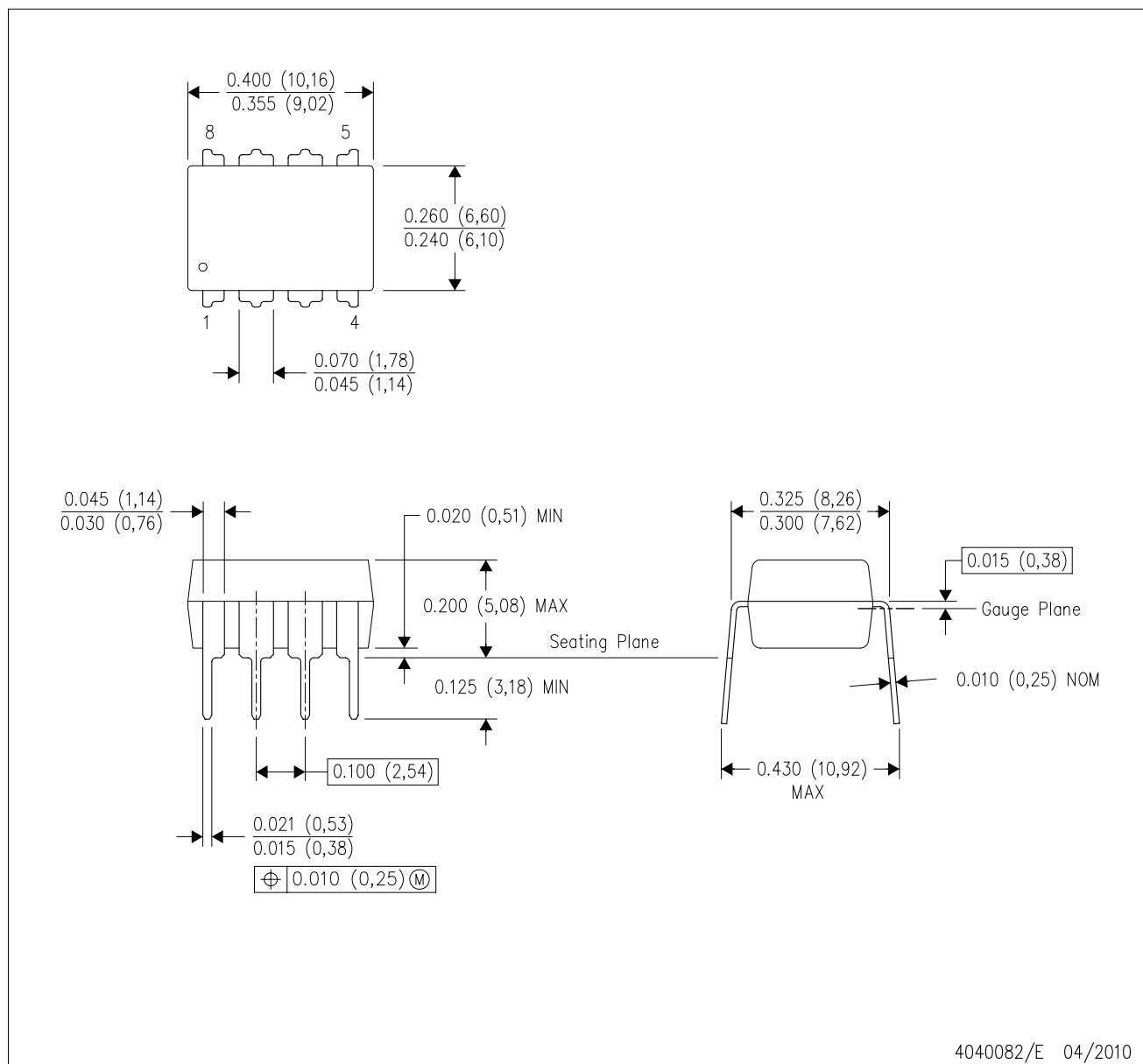
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

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